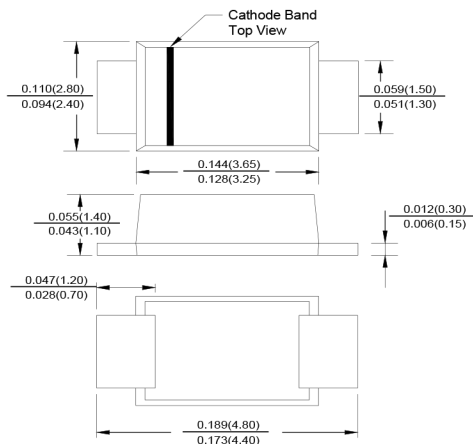


### SMAF



Dimensions in inches and (millimeters)

### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Fast switching for high efficiency
- ◆ Low reverse leakage
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:  
260°C/10 seconds at terminals
- ◆ Glass passivated chip junction

### MECHANICAL DATA

**Case:** JEDEC SMAF molded plastic body over passivated chip  
**Terminals:** Solder plated, solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Mounting Position:** Any

**Weight:** 0.0018 ounce, 0.064 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

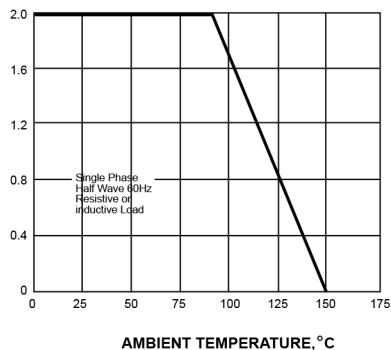
MDD Catalog Number	SYMBOLS	RS2AF	RS2BF	RS2DF	RS2GF	RS2JF	RS2KF	RS2MF	UNITS
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current at T <sub>L</sub> =90°C	I <sub>(AV)</sub>	2.0							Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	50.0							Amps
Maximum instantaneous forward voltage at 2.0A	V <sub>F</sub>	1.3							Volts
Maximum DC reverse current    T <sub>A</sub> =25°C at rated DC blocking voltage    T <sub>A</sub> =100°C	I <sub>R</sub>	5.0 50.0							μA
Maximum reverse recovery time    (NOTE 1)	t <sub>rr</sub>	150				250	500		ns
Typical junction capacitance (NOTE 2)	C <sub>J</sub>	50.0							pF
Typical thermal resistance (NOTE 3)	R <sub>θJA</sub>	20.0							°C/W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-50 to +150							°C

**Note:** 1. Reverse recovery condition  $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$   
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
3. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

# RATINGS AND CHARACTERISTIC CURVES RS2AF THRU RS2MF

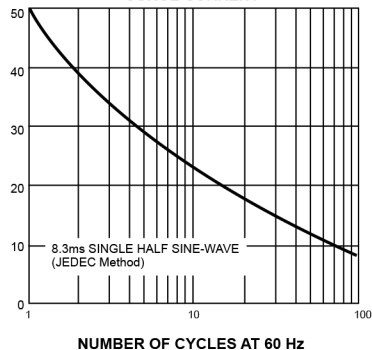
AVERAGE FORWARD RECTIFIED CURRENT,  
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



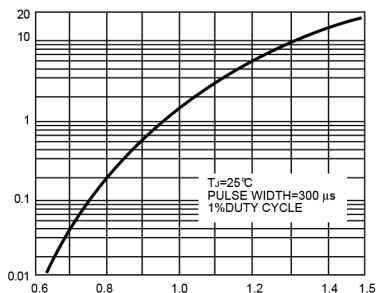
PEAK FORWARD SURGE CURRENT,  
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



INSTANTANEOUS FORWARD  
CURRENT, AMPERES

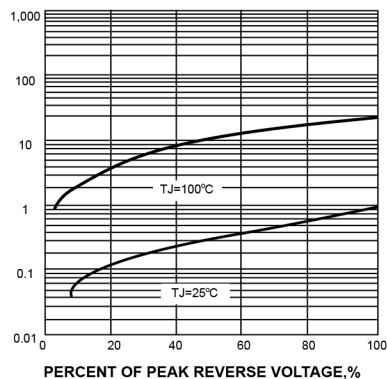
FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE,  
VOLTS

INSTANTANEOUS REVERSE CURRENT,  
MICROAMPERES

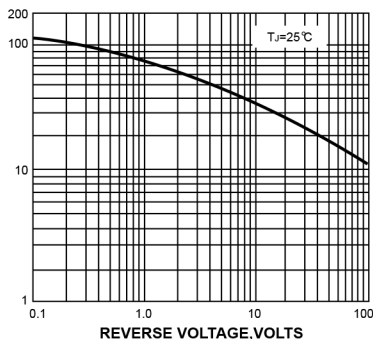
FIG. 4-TYPICAL REVERSE CHARACTERISTICS



PERCENT OF PEAK REVERSE VOLTAGE, %

JUNCTION CAPACITANCE, pF

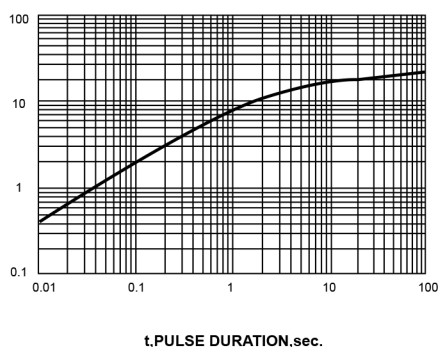
FIG. 5-TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE, VOLTS

TRANSIENT THERMAL IMPEDANCE,  
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



t, PULSE DURATION, sec.